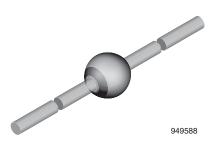


Vishay Semiconductors

Ultra-Fast Avalanche Sinterglass Diode



FEATURES

- · Glass passivated
- · Hermetically sealed axial leaded glass envelope
- Low reverse current
- · High reverse voltage

APPLICATIONS

• Switched mode power supplies

• High-frequency inverter circuits

- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

SOD-64

SOD-64

SOD-64

HALOGEN FREE

MECHANICAL DATA

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750,

method 2026

SF5406

SF5407

SF5408

Polarity: color band denotes cathode end

Mounting position: any Weight: approx. 858 mg

PARTS TABLE PART TYPE DIFFERENTIATION **PACKAGE** SF5400 $V_R = 50 \text{ V}; I_{FAV} = 3 \text{ A}$ SOD-64 SF5401 $V_R = 100 \text{ V}; I_{FAV} = 3 \text{ A}$ SOD-64 $V_R = 200 \text{ V}; I_{FAV} = 3 \text{ A}$ SF5402 SOD-64 SF5403 $V_R = 300 \ V; \ I_{FAV} = 3 \ A$ SOD-64 SF5404 $V_R = 400 \text{ V}; I_{FAV} = 3 \text{ A}$ SOD-64 SF5405 $V_{R} = 500 \text{ V}; I_{FAV} = 3 \text{ A}$ SOD-64 $V_R = 600 \text{ V}; I_{FAV} = 3 \text{ A}$

 $V_R = 800 \text{ V}; I_{FAV} = 3 \text{ A}$

 $V_R = 1000 \text{ V}; I_{FAV} = 3 \text{ A}$

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT		
Reverse voltage = repetitive peak reverse voltage		SF5400	$V_R = V_{RRM}$	50	V		
		SF5401	$V_R = V_{RRM}$	100	V		
		SF5402	$V_R = V_{RRM}$	200	V		
		SF5403	$V_R = V_{RRM}$	300	V		
	See electrical characteristics	SF5404	$V_R = V_{RRM}$	400	V		
		SF5405	$V_R = V_{RRM}$	500	V		
		SF5406	$V_R = V_{RRM}$	600	V		
		SF5407	$V_R = V_{RRM}$	800	V		
		SF5408	$V_R = V_{RRM}$	1000	V		
Peak forward surge current	t _p = 10 ms, half sine wave		I _{FSM}	150	Α		
Average forward current			I _{FAV}	3	Α		
Junction and storage temperature range			$T_j = T_{stg}$	- 55 to + 175	°C		
Non repetitive reverse avalanche energy	I _{(BR)R} = 0.4 A		E _R	10	mJ		

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MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	SYMBOL VALUE		
Junction ambient	Lead length I = 10 mm, T _L = constant	R_{thJA}	25	K/W	
	On PC board with spacing 25 mm	R_{thJA}	70	K/W	

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 3 A	SF5400	V _F	-	-	1.1	V
		SF5401	V _F	-	-	1.1	V
		SF5402	V _F	-	-	1.1	V
		SF5403	V _F	-	-	1.1	V
		SF5404	V _F	-	-	1.1	V
		SF5405	V _F	-	-	1.7	V
		SF5406	V _F	-	-	1.7	V
		SF5407	V _F	-	=	1.7	V
		SF5408	V _F	-	-	1.7	V
Reverse current	$V_R = V_{RRM}$		I _R	-	-	5	μΑ
	V _R = V _{RRM} , T _j = 125 °C		I _R	-	-	50	μA
Reverse breakdown voltage	I _R = 100 μA	SF5400	V(BR)R	60	-	-	V
		SF5401	V(BR)R	110	-	-	V
		SF5402	V(BR)R	220	-	-	V
		SF5403	V(BR)R	330	-	-	V
		SF5404	V(BR)R	440	-	-	V
		SF5405	V(BR)R	550	-	-	V
		SF5406	V(BR)R	660	-	-	V
		SF5407	V(BR)R	880	-	-	V
		SF5408	V(BR)R	1100	-	-	V
Reverse recovery time	I _F = 0.5 A, I _R = 1 A, i _R = 0.25 A	SF5400	t _{rr}	-	-	50	ns
		SF5401	t _{rr}	-	-	50	ns
		SF5402	t _{rr}	-	-	50	ns
		SF5403	t _{rr}	-	-	50	ns
		SF5404	t _{rr}	-	-	50	ns
		SF5405	t _{rr}	-	-	75	ns
		SF5406	t _{rr}	-	-	75	ns
		SF5407	t _{rr}	-	-	75	ns
		SF5408	t _{rr}	-	-	75	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

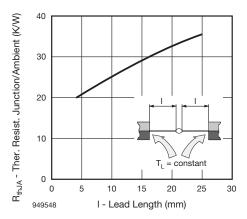


Fig. 1 - Max. Thermal Resistance vs. Lead Length

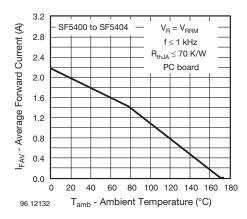


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature



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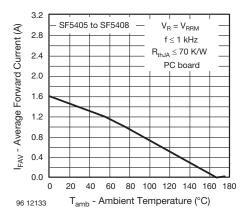


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

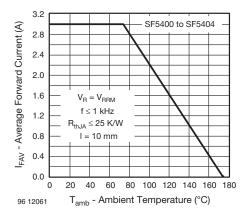


Fig. 4 - Max. Average Forward Current vs. Ambient Temperature

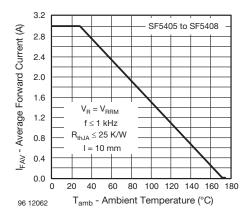


Fig. 5 - Max. Average Forward Current vs. Ambient Temperature

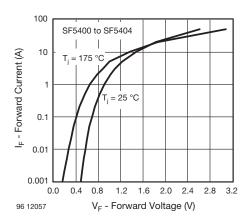


Fig. 6 - Max. Forward Current vs. Forward Voltage

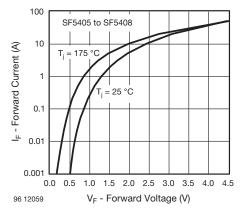


Fig. 7 - Max. Forward Current vs. Forward Voltage

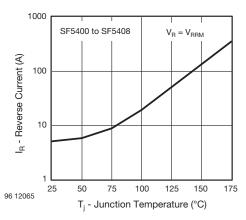


Fig. 8 - Max. Reverse Current vs. Junction Temperature

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Ultra-Fast Avalanche Sinterglass Diode



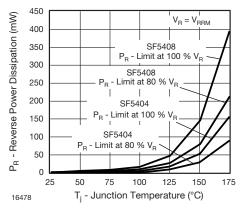


Fig. 9 - Max. Reverse Power Dissipation vs. Junction Temperature

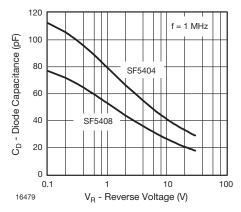
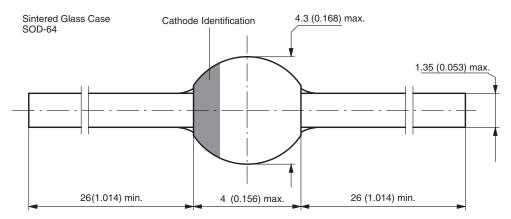


Fig. 10 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): SOD-64



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